TOSHIBA Transistor Silicon NPN Triple Diffused Type (Darlington)

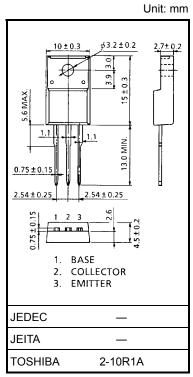
2SD1415A

High-Power Switching Applications
Hammer Drive, Pulse Motor Drive Applications

- High DC current gain: $h_{FE} = 2000$ (min) ($V_{CE} = 3$ V, $I_{C} = 3$ A)
- Low saturation voltage: V_{CE} (sat) = 1.5 V (max) (I_{C} = 3 A)

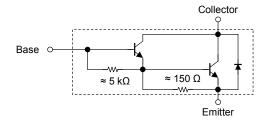
Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	120	V	
Collector-emitter voltage		V _{CEO}	100	V	
Emitter-base voltage		V _{EBO}	6	V	
Collector current	DC	Ic	7	А	
	Pulse	I _{CP}	10		
Base current		Ι _Β	0.7	Α	
Collector power dissipation	Ta = 25°C	Pc	2.0	W	
	Tc = 25°C	PC	25		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 1.7 g (typ.)

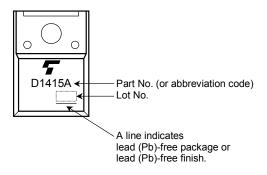
Equivalent Circuit

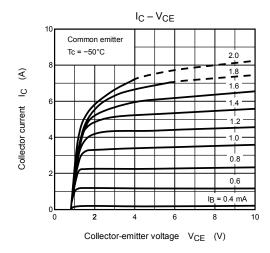


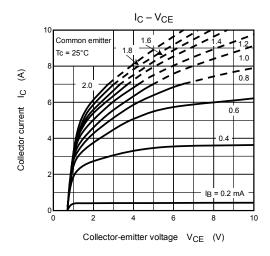
Electrical Characteristics (Tc = 25°C)

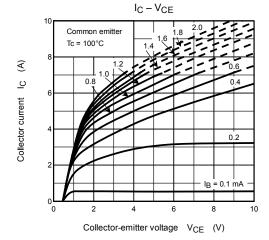
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 100 V, I _E = 0	_	_	100	μΑ
Emitter cut-off current		I _{EBO}	V _{EB} = 6 V, I _C = 0	0.75	_	3.0	mA
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 50 mA, I _B = 0	100	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 3 V, I _C = 3 A	2000	_	15000	
		h _{FE (2)}	V _{CE} = 3 V, I _C = 6 A	1000	_	_	
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 3 A, I _B = 6 mA	_	0.9	1.5	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 3 A, I _B = 6 mA	_	1.5	2.0	V
Switching time	Turn-on time	t _{on}	Output $20 \mu s$ B_{2} $V_{CC} \approx 45 V$ $I_{B1} = -I_{B2} = 6 \text{ mA, duty cycle} \le 1\%$	_	0.3	_	
	Storage time	t _{stg}		ı	5.1	_	μs
	Fall time	t _f		_	0.6	_	

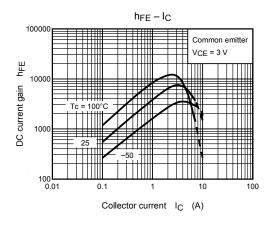
Marking

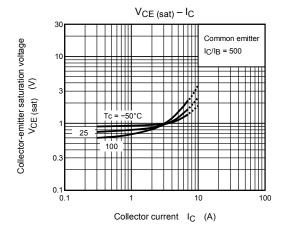


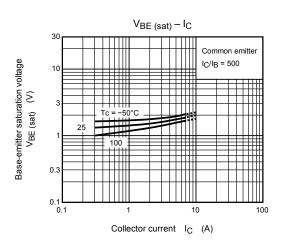


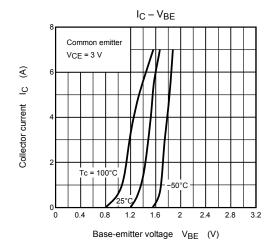


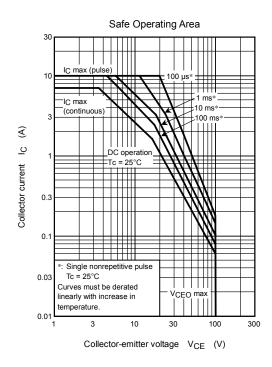












4 2004-07-26

RESTRICTIONS ON PRODUCT USE

030619EAA

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which
 may result from its use. No license is granted by implication or otherwise under any patent or patent rights of
 TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.

5 2004-07-26